

/ Descriptions

SOT-23 NPN Silicon NPN transistor in a SOT-23 Plastic Package.

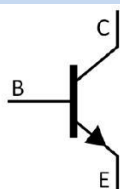
/ Features

， KTA1505
Excellent hFE linearity, complementary pair with KTA1505.

/ Applications

General amplifier and switching application.

/ Equivalent Circuit



/ Pinning



PIN 1 Base PIN 2 : Emitter PIN 3 Collector

/ h_{FE} Classifications & Marking

h _{FE} Classifications Symbol	O	Y	GR
h _{FE} Range	70 140	120 240	200 400
Marking	HWO	HWY	HWG

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	35	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current	I_C	500	mA
Base Current	I_B	50	mA
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 150	°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=35V$ $I_E=0$			0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=1.0V$ $I_C=100mA$	70		400	
	$h_{FE(2)}$	$V_{CE}=6.0V$ $I_C=400mA$	25			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA$ $I_B=10mA$		0.1	0.25	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=1.0V$ $I_C=100mA$		0.8	1.0	V
Transition Frequency	f_T	$V_{CE}=6.0V$ $I_C=20mA$		300		MHz
Collector Output Capacitance	C_{ob}	$V_{CE}=6.0V$ $f=1.0MHz$		7.0		pF

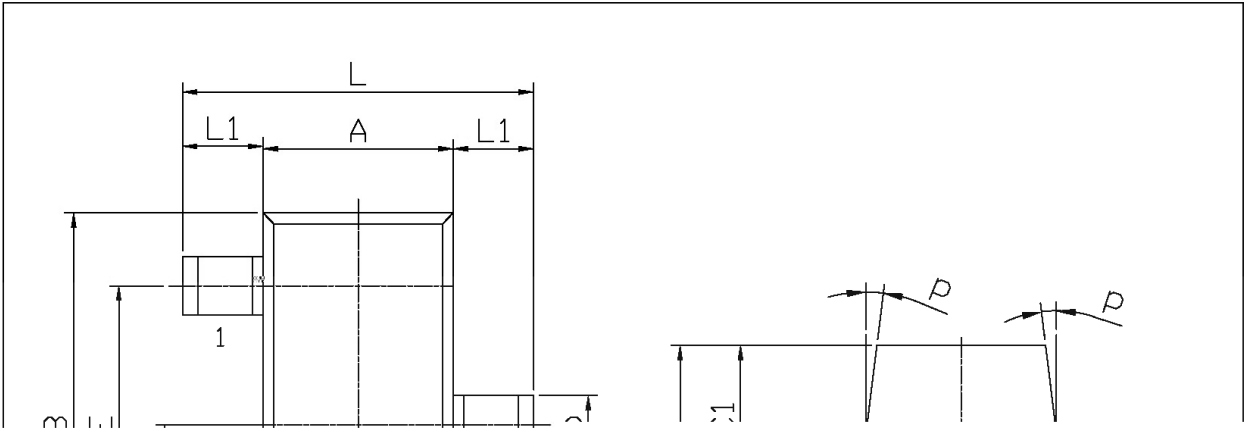
/ Electrical Characteristic Curve



/ Package Dimensions

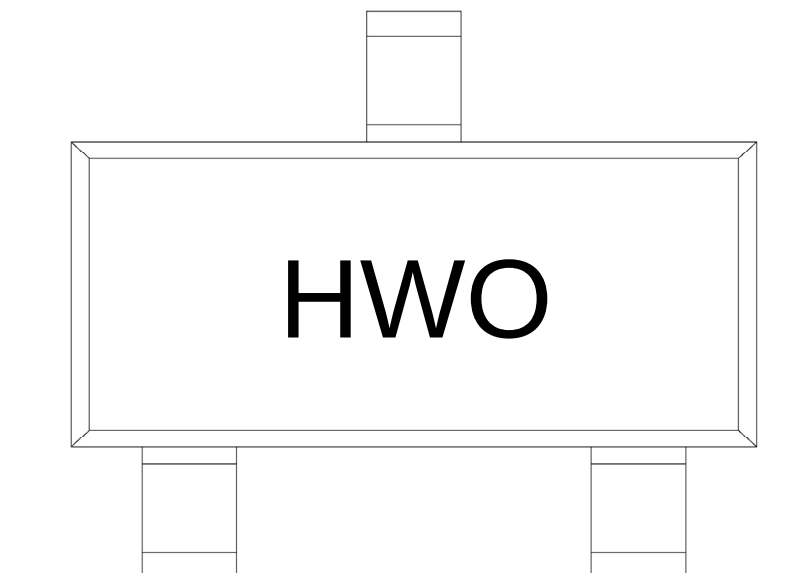
SOT-23

单位：mm



Symbol	Dimension	Value	Symbol	Value
E	1.70	2.10	M	0.20MIN
E1	0.85	1.05	D	7°

/ Marking Instructions



H

W

O h_{FE}

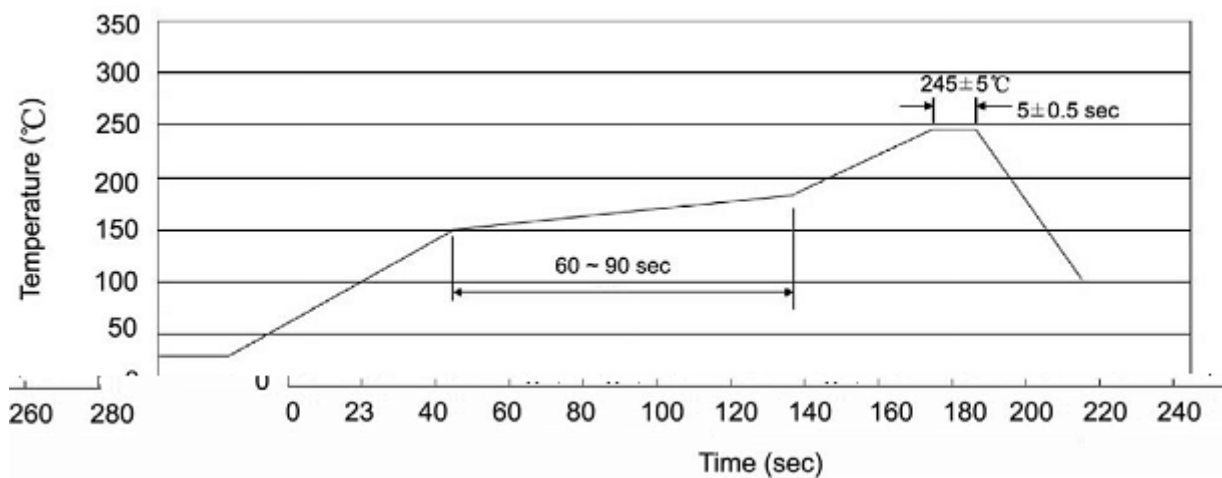
Note:

H Company Code

W Product Type

O h_{FE} Classifications Symbol

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

1 25 150 60